								F	REVIS	IONS										
LTR					С	ESCF	RIPTIO	N					D	ATE (Y	/R-MO-I	DA)		APPF	ROVE)
D	Cha	nged f	igure	1; Ren	noved	note 3 e type	for ca	ase ou	tlines	X and	Y. Add	ded		99-0	3-29		ŀ	<.A. C	ottong	im
REV SHEET																				
REV	D	D	D	D	D	D														
SHEET	15	16	17	18	19	20														
REV STATUS		•	•	RE'	v		D	D	D	D	D	D	D	D	D	D	D	D	D	D
OF SHEETS				SHI	EET		1	2	3	4	5	6	7	8	9	10	11	12	13	14
PMIC N/A					PAREI Steve L	DBY Dunc	can				1					NTER 0 4321			3	
STAN MICRO	CIR	CUI	Т		CKED lichae	BY I C. Jo	nes													
THIS DRAWIN	NG IS A SE BY	VAILAI ALL	BLE		ROVEI endall	D BY A. Co	ttongir	n		MIC 512	ROCI K X 8	IRCUI -BIT,	IT, ME Mon	EMOF OLITH	RY, DI HIC S	IGITA ILICO	L, FLA N	ASH E	PRO	Μ,
DEPAI AND AGEN DEPARTMEN		OF THE)4-22	ATE		SIZE	_		E COD			59	962-	966	92	
AMSC	N/A			REV	ISION	LEVEL				-	7	ַט	726	Ö						
)			SHE	ET	1		OF	2	0				
DSCC FORM 22:	33																			

5962-E190-99

<u>DISTRIBUTION STATEMENT A</u>. Approved for public release; distribution is unlimited.

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- 1.1 <u>Scope</u>. This drawing documents five product assurance classes, class D (lowest reliability), class E, (exceptions), class G (lowest high reliability), class H (high reliability), and class K, (highest reliability) and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of radiation hardness assurance levels are reflected in the PIN.
 - 1.2 PIN. The PIN shall be as shown in the following example:

5962	-	96692	<u>01</u>	<u>H</u>	<u>X</u>	<u>X</u>
Federal stock class designator	RHA designator (see 1.2.1) / wing number	/	Device type (see 1.2.2)	Device class designator (see 1.2.3)	Case outline (see 1.2.4)	Lead finish (see 1.2.5)

- 1.2.1 <u>Radiation hardness assurance (RHA) designator</u>. Device classes H and K RHA marked devices shall meet the MIL-PRF-38534 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 <u>Device type(s)</u>. The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function	Access time
01	WMF512K8-150, ACT-F512K8N-150	FLASH EPROM. 512K X 8-bit	150 ns
02	WMF512K8-120, ACT-F512K8N-120	FLASH EPROM, 512K X 8-bit	120 ns
03	WMF512K8-90, ACT-F512K8N-090	FLASH EPROM, 512K X 8-bit	90 ns
04	WMF512K8-70, ACT-F512K8N-070	FLASH EPROM, 512K X 8-bit	70 ns

1.2.3 <u>Device class designator</u>. This device class designator shall be a single letter identifying the product assurance level as follows:

Device class

Device performance documentation

D, E, G, H, or K

Certification and qualification to MIL-PRF-38534

1.2.4 <u>Case outline(s)</u>. The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
Т	See figure 1	32	Ceramic flatpack, lead formed
U	See figure 1	32	Ceramic flatpack
Χ	See figure 1	32	Co-fired ceramic, single cavity, dual-in-line
Υ	See figure 1	32	Co-fired ceramic, single cavity, SOJ

1.2.5 Lead finish. The lead finish shall be as specified in MIL-PRF-38534.

STANDARD
MICROCIRCUIT DRAWING
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43216-5000

SIZE
A

5962-96692

REVISION LEVEL
D
SHEET
2

1.3 Absolute maximum ratings. 1/

1.4 Recommended operating conditions.

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbook.</u> The following specification, standards, and handbook form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38534 - Hybrid Microcircuits, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

MIL-STD-973 - Configuration Management. MIL-STD-1835 - Microcircuit Case Outlines.

HANDBOOK

DEPARTMENT OF DEFENSE

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbook are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

- Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- Minimum DC voltage in input or I/O pins is -0.5 V dc. During voltage transitions, inputs may overshoot V_{SS} to -2.0 V dc for periods up to 20 ns. Maximum DC voltage on output and I/O pins is V_{CC} +0.5 V dc. During voltage transitions, outputs may overshoot to V_{CC} +2.0 V dc for periods up to 20 ns.
- may overshoot to V_{CC} +2.0 V dc for periods up to 20 ns.

 Minimum DC input voltage on A9 is -0.5 V dc. During voltage transitions, A9 may overshoot V_{SS} to -2.0 V dc for periods up to 20 ns. Maximum DC input voltage on A9 is +13.5 V dc which may overshoot to +14.0 V dc for periods up to 20 ns.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		D	3

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item performance requirements for device classes D, E, G, H, and K shall be in accordance with MIL-PRF-38534. Compliance with MIL-PRF-38534 may include the performance of all tests herein or as designated in the device manufacturer's Quality Management (QM) plan or as designated for the applicable device class. Therefore, the tests and inspections herein may not be performed for the applicable device class (see MIL-PRF-38534). Futhermore, the manufacturers may take exceptions or use alternate methods to the tests and inspections herein and not perform them. However, the performance requirements as defined in MIL-PRF-38534 shall be met for the applicable device class.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38534 and herein.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein and figure 1.
 - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.
 - 3.2.3 Truth table(s). The truth table(s) shall be as specified on figure 3.
 - 3.2.4 Timing diagram(s). The timing diagram(s) shall be as specified on figures 4, 5, and 6.
 - 3.2.5 Block diagram. The block diagram shall be as specified on figure 7.
 - 3.2.6 Output load circuit. The output load circuit shall be as specified on figure 8.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full specified operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.
- 3.5 <u>Programming procedure</u>. The programming procedure shall be as specified by the manufacturer and shall be available upon request.
- 3.6 <u>Marking of Device(s)</u>. Marking of device(s) shall be in accordance with MIL-PRF-38534. The device shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's vendor similar PIN may also be marked as listed in QML-38534.
- 3.7 <u>Data</u>. In addition to the general performance requirements of MIL-PRF-38534, the manufacturer of the device described herein shall maintain the electrical test data (variables format) from the initial quality conformance inspection group A lot sample, for each device type listed herein. Also, the data should include a summary of all parameters manually tested, and for those which, if any, are guaranteed. This data shall be maintained under document revision level control by the manufacturer and be made available to the preparing activity (DSCC-VA) upon request.

STANDARD
MICROCIRCUIT DRAWING
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43216-5000

SIZE A		5962-96692
	REVISION LEVEL D	SHEET 4

- 3.8 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to supply to this drawing. The certificate of compliance (original copy) submitted to DSCC-VA shall affirm that the manufacturer's product meets the performance requirements of MIL-PRF-38534 and herein.
- 3.9 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38534 shall be provided with each lot of microcircuits delivered to this drawing.
- 3.10 Endurance. A reprogrammability test shall be completed as part of the vendor's reliability monitors. This reprogrammability test shall be done for the initial characterization and after any design process changes which may affect the reprogrammability of the device. The methods and procedures may be vendor specific, but shall guarantee the number of program/erase cycles listed in section 1.3 herein over the full military temperature range. The vendors procedure shall be kept under document control and shall be made available upon request of the acquiring or preparing activity.
- 3.11 <u>Data retention</u>. A data retention stress test shall be completed as part of the vendor's reliability monitors. This test shall be done for initial characterization and after any design or process change which may affect data retention. The methods and procedures may be vendor specific, but shall guarantee the number of years listed in section 1.3 herein over the full military temperature range. The vendor's procedure shall be kept under document control and shall be made available upon request of the acquiring or preparing activity.

4. QUALITY ASSURANCE PROVISIONS

- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38534 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.
 - 4.2 Screening. Screening shall be in accordance with MIL-PRF-38534. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to either DSCC-VA or the acquiring activity upon request. Also, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) T_A as specified in accordance with table I of method 1015 of MIL-STD-883.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 <u>Conformance and periodic inspections</u>. Conformance inspection (CI) and periodic inspection (PI) shall be in accordance with MIL-PRF-38534 and as specified herein.

STANDARD
MICROCIRCUIT DRAWING
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43216-5000

SIZE
A

SP62-96692

REVISION LEVEL
D
SHEET
5

Test	Symbol	Conditions <u>1</u> / <u>2</u> / -55 C T _C +125 C	Group A subgroups	Device type	Limits		Unit -
		unless otherwise specified		71	Min	Max	
DC parameters							
Input leakage current	I _{LI}	$V_{CC} = 5.5 \text{ V dc}, V_{IN} = \text{GND}$ to V_{CC}	1,2,3	All		10	Α
Output leakage current	I _{LO}	V_{CC} = 5.5 V dc, V_{IN} = GND to V_{CC}	1,2,3	All		10	Α
V _{CC} active current for read	I _{CC1}	$\overline{CS} = V_{ L}, \overline{OE} = V_{ H},$ $f = 5 \text{ MHz}, V_{CC} = 5.5 \text{ V dc}$	1,2,3	All		35	mA
V _{CC} active current for program or erase <u>3</u> /	I _{CC2}	CS = V _{II} , OE = V _{IH} , V _{CC} = 5.5 V dc	1,2,3	All		50	mA
V _{CC} standby current	I _{SB}	V _{CC} = 5.5 V dc, CS = V _{IH} , f = 5 MHz	1,2,3	All		1.6	mA
Input low level 3/	v_{IL}		1,2,3	All		0.8	V
Input high level 3/	v _{IH}		1,2,3	All	2.0		V
Output low voltage	V _{OL}	$V_{CC} = 4.5 \text{ V dc}, I_{OL} = 8.0 \text{ m}$	A 1,2,3	All		0.45	V
Output high voltage	V _{OH1}	V _{CC} = 4.5 V dc, I _{OH} = -2.5 mA	1,2,3	All	0.85 × ^V CC		V
Dynamic characteristics							
Address capacitance 3/	C _{AD}	$V_{IN} = 0 \text{ V dc, f} = 1.0 \text{ MHz,}$ $T_A = +25 \text{ C}$	4	All		15	pF
Output enable 3/ capacitance	C _{OE}	$V_{IN} = 0 \text{ V dc}, f = 1.0 \text{ MHz},$ $T_A = +25 \text{ C}$	4	All		15	pF
See footnotes at end of to	able.						
	STANDAR		SIZE A			59	62-9669
MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		TER COLUMBUS		REVISION	I LEVEL	SHEE	 T 6

Test	Symbol	Conditions <u>1</u> / <u>2</u> / -55 C T _C +125 C unless otherwise specified	Group A subgroups	Device type	Limits		Unit -	
		unless otherwise specified			Min	Max		
Dynamic characteristics -	Continue	d.						
Write enable <u>3</u> / capacitance	c_{WE}	$V_{IN} = 0 V dc, f = 1.0 MHz,$ $T_A = +25 C$	4	All		15	pF	
Chip select <u>3</u> / capacitance	c _{cs}	$V_{IN} = 0 \text{ V dc, f} = 1.0 \text{ MHz,}$ $T_A = +25 \text{ C}$	4	All		15	pF	
Data I/O capacitance 3/	C _{I/O}	V _{IN} = 0 V dc, f = 1,0 MHz, T _A = +25 C	4	All		15	pF	
Functional testing								
Functional tests		See 4.3.1c	7,8A,8B	All				
Read cycle AC timing cha	aracteristic	es						
Read cycle time 3/	^t RC	See figure 4	9,10,11	01 02 03 04	150 120 90 70		ns	
Address access time	^t ACC	See figure 4	9,10,11	01 02 03 04		150 120 90 70	ns	
Chip select access time	^t CE	See figure 4	9,10,11	01 02 03 04		150 120 90 70	ns	
Output enable to output valid	^t OE	See figure 4	9,10,11	01 02 03, 04		55 50 35	ns	
Output h <u>old from</u> 3/ address, CS or OE change, whichever is first	^t OH	See figure 4	9,10,11	All	0		ns	
See footnotes at end of ta	able.							
	STANDAR SIRCUIT D		SIZE A			59	962-9669	
DEFENSE SUP	PLY CENT	FER COLUMBUS 43216-5000		REVISION	LEVEL D	SHE	ET 7	

	TA	ABLE I. <u>Electrical performance</u>	characteristics -	Continued	•		
Test	Symbol	Conditions <u>1</u> / <u>2</u> / -55 C T _C +125 C	Group A subgroups	Device type	Limits		Unit -
		unless otherwise specified			Min	Max	
Write/Erase/Program AC	C timing cha	aracteristics WE controlled.					
Write cycle time <u>3</u> /	^t WC	See figure 5	9,10,11	01 02 03 04	150 120 90 70		ns
Chip select setup time	^t cs	See figure 5	9,10,11	All	0		ns
Write enable pulse width	^t WP	See figure 5	9,10,11	01, 02	50 45		_ ns
Address setup time	^t AS	See figure 5	9,10,11	All	0		ns
Data setup time	^t DS	See figure 5	9,10,11	01, 02	50		_ ns
				03, 04	45		
Data hold time	^t DH	See figure 5	9,10,11	All	0		ns
Address hold time	^t AH	See figure 5	9,10,11	01, 02	50		_ ns
				03, 04	45		
Write enable pulse 3/ width high	^t WPH	See figure 5	9,10,11	All	20		ns

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL D	SHEET 8

Symbol	-55 C T _C +125 C	Group A subgroups	Device type	Limits		Unit –
unless otherwise specified	3 1	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	Min	Max		
<u>charateris</u>	tics CS controlled.					
^t WC	See figure 6	9,10,11	01 02 03 04	150 120 90 70		ns
^t ws	See figure 6	9,10,11	All	0		ns
^t CP	See figure 6	9,10,11	01, 02	50 45		_ ns
^t AS	See figure 6	9,10,11	All	0		ns
^t DH	See figure 6	9,10,11	All	0		ns
^t DS	See figure 6	9,10,11	01, 02	50		_ ns
			03, 04	45		
^t AH	See figure 6	9,10,11	01, 02	50		_ ns
			03, 04	45		
	tws tCP tAS tDH tDS	two See figure 6 to See figure 6	unless otherwise specified charateristics	twc See figure 6 9,10,11 01 02 03 04 tws See figure 6 9,10,11 All t_CP See figure 6 9,10,11 All t_DH See figure 6 9,10,11 All t_DS See figure 6 9,10,11 All t_DS See figure 6 9,10,11 All t_DS See figure 6 9,10,11 O1, 02 O3, 04 t_AH See figure 6 9,10,11 O1, 02 O3, 04	two See figure 6 g,10,11 o1, 02 o3 o3 o4 for o3, 04 d5 the see figure 6 g,10,11 All o the see figure 6 g,10,11 o1, 02 o3 o3 o4 d5 day the see figure 6 g,10,11 o1, 02 o3 o3 o4 d5 o4 o4 o4 o4 o4 o4 o4 o4 o4 o	two See figure 6 two See figure 6 two See figure 6 the See figu

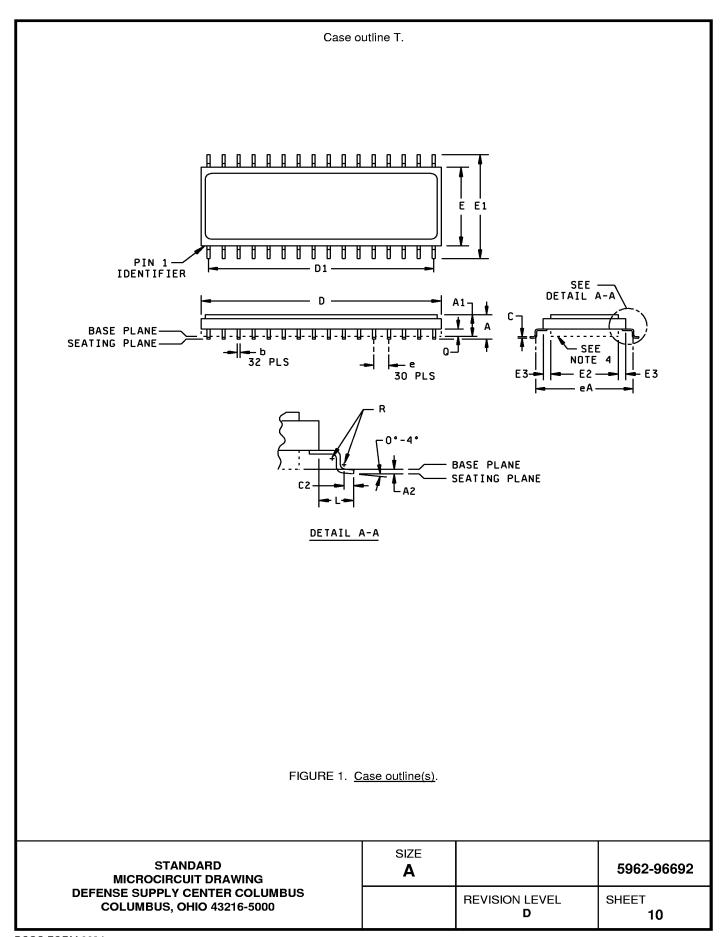
 $^{1\!\!/}$ Unless otherwise specified, 4.5 V dc $\,$ V $_{CC}$ $\,$ 5.5 V dc and V $_{SS}$ = 0 V. $2\!\!/$ Unless otherwise specified, the DC test conditions are as follows: Input pulse levels: V $_{IH}$ = V $_{CC}$ - 0.3 V and V $_{IL}$ = 0.3 V. Unless otherwise specified, the AC test conditions are as follows:

Input pulse levels: $V_{IL} = 0$ V and $V_{IH} = 3.0$ V. Input rise and fall times: 5 nanoseconds.

Input and output timing reference levels: 1.5 V.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		D	9

^{3/} Parameters shall be tested as part of device characterization and after design and process changes. Parameters shall be tested to the limits specified in table I for all lots not specifically tested.



Case outline T - Continued.

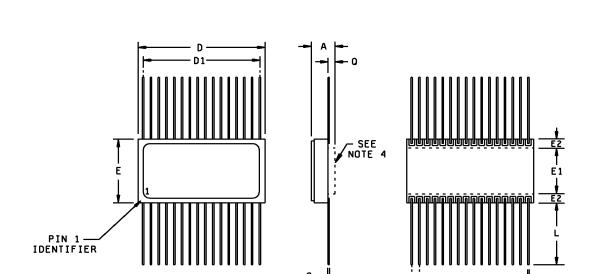
Symbol	Millimeters		Inc	hes
	Min	Max	Min	Max
A		3.35		.132
A1	2.41	3.18	.095	.125
A2	0.08	0.18	.003	.007
b	0.38	0.48	.015	.019
С	0.10	0.18	.004	.007
C2	0.76 TYP		.030 TYP	
D	20.57	21.08	.810	.830
D1	19.05 TYP		.750 TYP	
Е	10.29	10.54	.405	.415
E1	13.34	13.59	.525	.535
E2	7.75	8.00	.305	.315
E3	1.27	TYP	.050 TYP	
eA	11.0	7 TYP	.436 TYP	
е	1.27 TYP		.050 TYP	
L	1.52 TYP		.060	TYP
Q	0.56	0.71	.022	.028
R	0.18	TYP	.007	TYP

NOTES

- 1. The U.S preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. For solder lead finish, dimensions b and C will increase by +.003 inches (+0.08 mm).
- 3. Pin numbers are for reference only.
- 4. The case outline T is available in either a pedestal or non-pedestal package. The Q dimension only applies to the pedestal version of case outline T.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		D	11



Case outline U.

Symbol	Millimeters		Inc	hes
	Min	Max	Min	Max
Α		3.18		.125
b	0.38	0.48	.015	.019
С	0.10	0.18	.004	.007
D	20.57	21.08	.810	.830
D1	19.05 TYP		.750 TYP	
E	10.29	10.54	.405	.415
E1	7.75	8.00	.305	.315
E2	1.27 TYP		.050	TYP
е	1.27 TYP		.050	TYP
L	9.65	10.67	.380	.420
Q	0.56	0.71	.022	.028

NOTES:

- 1. The U.S preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. For solder lead finish, dimensions b and C will increase by +.003 inches (+0.08 mm).
- Pin numbers are for reference only.
 The case outline U is available in either a pedestal or non-pedestal package. The Q dimension only applies to the pedestal version of case outline U.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL D	SHEET 12

Case outline X. Description of the print of

Symbol	Millimeters		Inc	hes
	Min	Max	Min	Max
Α	3.56	5.08	.140	.200
A1	0.48	1.19	.019	.047
A2	3.18	4.90	.125	.193
В	0.20	0.30	.009	.012
B1	14.94	15.67	.588	.617
D	42.01	42.82	1.654	1.686
D1	14.73	15.37	.580	.605
D2	37.90	38.30	1.492	1.508
е	2.54 BSC		.100	BSC
e1	0.41	0.51	.016	.020

NOTES:

- 1. The U.S preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. For solder lead finish, dimensions B and e1 will increase by +.003 inches (+0.08mm).
- 3. Pin numbers are for reference only.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		D	13

Symbol	Millimeters		Inc	hes
	Min	Max	Min	Max
Α	2.67	4.06	.105	.160
A1	1.02	1.52	.040	.060
B1	9.30	9.80	.366	.386
С	0.15	0.25	.006	.010
D	20.83	21.35	.820	.840
D1	10.80	11.05	.425	.435
D2	18.85	19.25	.742	.758
е	1.27 BSC		.050	BSC
e1	0.38	0.48	.015	.019
R	8.89	8.89 BSC		BSC

NOTES:

- 1. The U.S preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin numbers are for reference only.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		D	14

Device types	All	Device types	All
Case outlines	All	Case outlines	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	A18	17	I/O3
2	A16	18	I/O4
3	A15	19	I/O5
4	A12	20	I/O6
5	A 7	21	1/07
6	A6	22	c s
7	A5	23	A10
8	A 4	24	ŌĒ
9	АЗ	25	A11
10	A2	26	A9
11	A1	27	A8
12	A0	28	A13
13	I/O0	29	A14
14	I/O1	30	A17
15	I/O2	31	WE
16	Ground	32	v _{cc}

FIGURE 2. <u>Terminal connections</u>.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-96692
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		D	15

cs	OE	WE	I/O	MODE
V _{IL}	V _{IL}	٧ _{IH}	D _{OUT}	Read
V_{IL}	> _{IH}	v _{IL}	D _{IN}	Write
v_IH	Х	Х	High Z	Standby
V_{IL}	>II	v _{IH}	High Z	Output disable

NOTES:

- V_{IH} = High logic level
 V_{IL} = Low logic level
 X = Do not care (either high or low)
 High Z = High impedance state

FIGURE 3. Truth table.

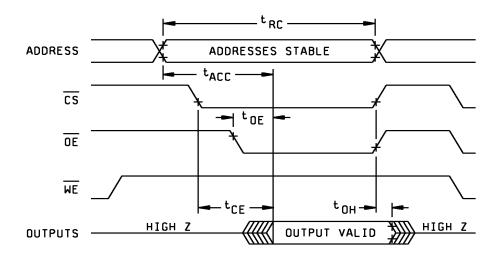


FIGURE 4. Read cycle timing diagram.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-96692
		REVISION LEVEL D	SHEET 16

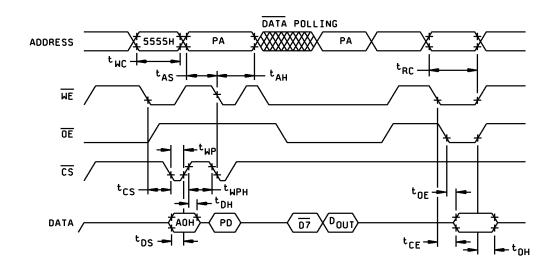


FIGURE 5. Write cycle timing diagram, WE controlled.

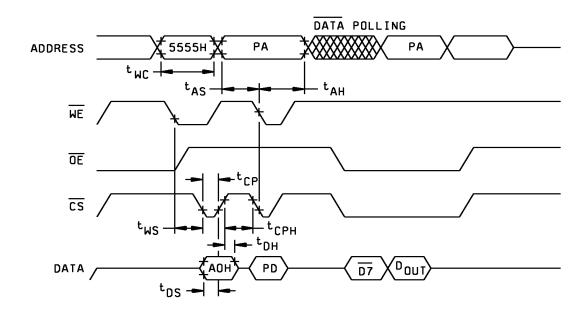


FIGURE 6. Write cycle timing diagram, CS controlled.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-96692
		REVISION LEVEL D	SHEET 17

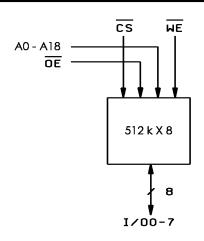
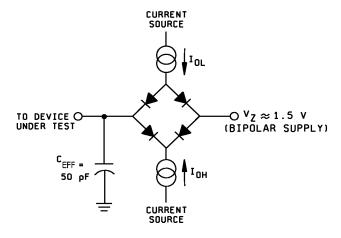


FIGURE 7. Block diagram.



Parameter	Тур.	Unit
Input pulse level	0 - 3.0	٧
Input rise and fall	5	ns
Input and output reference level	1.5	٧
Output load capacitance	50	pF

NOTES:

- V_Z is programmable from +2 V to +7 V.
 I_{OL} and I_{OH} are programmable from 0 to 16 mA.
 Tester impedance is Z₀ = 75 ohms.
 V_Z is typically the midpoint of V_{OH} and V_{OH}.
 I_{OI} and I_{OH} are adjusted to simulate a typical resistive load circuit.
 ATE tester includes jig capacitance.

FIGURE 8. Output load circuit.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-96692
		REVISION LEVEL D	SHEET 18

TABLE II. Electrical test requirements.

MIL-PRF-38534 test requirements	Subgroups (in accordance with MIL-PRF-38534, group A test table)
Interim electrical parameters	1,4,7,9
Final electrical parameters	1*,2,3,4,7,8A,8B,9,10,11
Group A test requirements	1,2,3,4,7,8A,8B,9,10,11
Group C end-point electrical parameters	1,2,3,4,7,8A,8B,9,10,11
MIL-STD-883, group E end-point electrical parameters for RHA devices	Subgroups** (in accordance with method 5005, group A test table)

- * PDA applies to subgroup 1.
- ** When applicable to this standard microcircuit drawing, the subgroups shall be defined.
- 4.3.1 Group A inspection (CI). Group A inspection shall be in accordance with MIL-PRF-38534 and as follows:
 - Tests shall be as specified in table II herein.
 - b. Subgroups 5 and 6 shall be omitted.
 - c. Subgroups 7 and 8 shall include verification of the truth table on figure 3.
- 4.3.2 Group B inspection (PI). Group B inspection shall be in accordance withMIL-PRF-38534.
- 4.3.3 Group C inspection (PI). Group C inspection shall be in accordance with MIL-PRF-38534 and as follows:
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test, method 1005 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to either DSCC-VA or the acquiring activity upon request. Also, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - (2) T_A as specified in accordance with table I of method 1005 of MIL-STD-883.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-96692
		REVISION LEVEL D	SHEET 19

- 4.3.4 Group D inspection (PI). Group D inspection shall be in accordance with MIL-PRF-38534.
- 4.3.5 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels shall be M, D, R, and H. RHA quality conformance inspection sample tests shall be performed at the RHA level specified in the acquisition document.
 - a. RHA tests for levels M, D, R, and H shall be performed through each level to determine at what levels the devices meet the RHA requirements. These RHA tests shall be performed for initial qualification and after design or process changes which may affect the RHA performance of the device.
 - b. End-point electrical parameters shall be as specified in table II herein.
 - c. Prior to total dose irradiation, each selected sample shall be assembled in its qualified package. It shall pass the specified group A electrical parameters in table I for subgroups specified in table II herein.
 - d. The devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38534 for RHA level being tested, and meet the postirradiation end-point electrical parameter limits as defined in table I at T_A = +25 C ±5 percent, after exposure.
 - e. Prior to and during total dose irradiation testing, the devices shall be biased to establish a worst case condition as specified in the radiation exposure circuit.
 - f. For device classes H and K, subgroups 1 and 2 in table V, method 5005 of MIL-STD-883 shall be tested as appropriate for device construction.
 - g. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.
 - 5. PACKAGING
 - 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38534.
 - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0526.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0512.
- 6.6 <u>Sources of supply</u>. Sources of supply are listed in QML-38534. The vendors listed in QML-38534 have submitted a certificate of compliance (see 3.7 herein) to DSCC-VA and have agreed to this drawing.

STANDARD
MICROCIRCUIT DRAWING
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43216-5000

SIZE A		5962-96692
	REVISION LEVEL D	SHEET 20

STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN

DATE: 99-03-29

Approved sources of supply for SMD 5962-96692 are listed below for immediate acquisition only and shall be added to QML-38534 during the next revision. QML-38534 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of QML-38534.

Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN <u>1</u> /	number	PIN <u>2</u> /
5962-9669201HTA	54230	WMF512K8-150FFQ5
5962-9669201HUA	54230	WMF512K8-150FFQ5
5962-9669201HUC	54230	WMF512K8-150FEQ5
5962-9669201HUC	54230	WMF512K8-150FEQ5
5962-9669201HXA	54230	WMF512K8-150CQ5
5962-9669201HXA	88379	ACT-F512K8N-150P4Q
5962-9669201HXC	54230	WMF512K8-150CQ5
5962-9669201HXC	88379	ACT-F512K8N-150P4Q
5962-9669201HYA	54230	WMF512K8-150DEQ5
5962-9669201HYA	54230	WMF512K8-150DEQ5
5962-9669202HTA	54230	WMF512K8-120FFQ5
5962-9669202HTC	54230	WMF512K8-120FFQ5
5962-9669202HUA	54230	WMF512K8-120FEQ5
5962-9669202HUC	54230	WMF512K8-120FEQ5
5962-9669202HXA	88379	ACT-F512K8N-120P4Q
5962-9669202HXA	54230	WMF512K8-120CQ5
5962-9669202HXC	88379	ACT-F512K8N-120P4Q
5962-9669202HXC	54230	WMF512K8-120CQ5
5962-9669202HYA	54230	WMF512K8-120DEQ5
5962-9669202HYA	54230	WMF512K8-120DEQ5
5962-9669203HTA	54230	WMF512K8-90FFQ5
5962-9669203HTC	54230	WMF512K8-90FFQ5
5962-9669203HUC	54230	WMF512K8-90FEQ5
5962-9669203HUC	54230	WMF512K8-90FEQ5
5962-9669203HXA	54230	WMF512K8-90CQ5
5962-9669203HXA	88379	ACT-F512K8N-090P4Q
5962-9669203HXC	54230	WMF512K8-90CQ5
5962-9669203HXC	88379	ACT-F512K8N-090P4Q
5962-9669203HYA	54230	WMF512K8-90DEQ5
5962-9669203HYC	54230	WMF512K8-90DEQ5
5962-9669204HTA	54230	WMF512K8-70FFQ5
5962-9669204HTC	54230	WMF512K8-70FFQ5
5962-9669204HUA	54230	WMF512K8-70FEQ5
5962-9669204HUC	54230	WMF512K8-70FEQ5
5962-9669204HXA	54230	WMF512K8-70CQ5
5962-9669204HXA	88379	ACT-F512K8N-070P4Q
5962-9669204HXC	54230	WMF512K8-70CQ5
5962-9669204HXC	88379	ACT-F512K8N-070P4Q
5962-9669204HYA	54230	WMF512K8-70DEQ5
5962-9669204HYC	54230	WMF512K8-70DEQ5

The lead finish shown for each PIN representing a hermetic package is available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.

<u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN - Continued.

DATE: 99-03-29

Vendor CAGE
numberVendor name
and address54230White Electronic Designs Corporation
3601 East University Drive.
Phoenix, AZ 8503488379Aeroflex Circuit Technology Corporation
35 South Service Road
Plainview, NY 11803

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2 of 2